

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

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Application No.: New U.S. Patent Application

Filed: May 30, 2001

Docket No.: 109677

For: MEMORY DEVICE

PRELIMINARY AMENDMENT

Director of the U.S. Patent and Trademark Office
Washington, D. C. 20231

Sir:

Prior to initial examination, please amend the above-identified application as follows:

IN THE CLAIMS:

Please replace claims 3, 5, 10 as follows:

3. (Amended) A memory device as claimed in claim 1, wherein a common electrode is provided between two layers, an input electrode is provided on one of the layers and an output electrode is provided on the other of the layers, the input and output electrodes being disposed on opposite sides of their respective layers compared with the common electrode.

5. (Amended) A memory device comprising a plurality of devices as claimed in claim 1.

10. (Amended) A method as claimed in claim 7, wherein the step of detecting the said resultant voltage comprising the phase of the said resultant voltage with the phase of the said applied non-polarising voltage.

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Please add new claims 11-16 as follows:

--11 A memory device as claimed in claim 2, wherein a common electrode is provided between two layers, an input electrode is provided on one of the layers and an output electrode is provided on the other of the layers, the input and output electrodes being disposed on opposite sides of their respective layers compared with the common electrode.--

--12. A memory device comprising a plurality of devices as claimed in claim 2.--

--13. A memory device comprising a plurality of devices as claimed in claim 3.--

--14. A memory device comprising a plurality of devices as claimed in claim 4.--


--15. A method as claimed in claim 8, wherein the step of detecting the said resultant voltage comprising the phase of the said resultant voltage with the phase of the said applied non-polarising voltage.--

--16. A method as claimed in claim 9, wherein the step of detecting the said resultant voltage comprising the phase of the said resultant voltage with the phase of the said applied non-polarising voltage.--

REMARKS

Claims 1-16 are pending. Claims 3, 5, and 10 are amended to eliminate multiple dependencies and claims 11-16 are amended to compensate for the subject matter deleted from claims 3, 5, and 10. The attached Appendix includes marked-up copies of each rewritten claim (37 C.F.R. 1.121(c)(1)(ii)). Prompt and favorable consideration on the merits is respectfully requested.

Respectfully submitted,


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Attachment
Appendix

Date: May 30, 2001

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DEPOSIT ACCOUNT USE AUTHORIZATION Please grant any extension necessary for entry; Charge any fee due to our Deposit Account No. 15-0461
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APPENDIX

Changes to Claims:

The following are marked-up versions of the amended claims:

3. (Amended) A memory device as claimed in claim 1 ~~or claim 2~~, wherein a common electrode is provided between two layers, an input electrode is provided on one of the layers and an output electrode is provided on the other of the layers, the input and output electrodes being disposed on opposite sides of their respective layers compared with the common electrode.

5. (Amended) A memory device comprising a plurality of devices as claimed in ~~any preceding claim~~ claim 1.

10. (Amended) A method as claimed in ~~any of claims 7 to 9~~ claim 7, wherein the step of detecting the said resultant voltage comprising the phase of the said resultant voltage with the phase of the said applied non-polarising voltage.

Claims 11-16 are added.